

■ Product introduction

SN74LVC1G00 is a 2-input NAND integrated circuit, which can realize the mathematical logic operation of $Y = \overline{A+B}$ and $Y = \overline{A*B}$. Advanced CMOS process design is adopted, which has the working characteristics of low power consumption and high output driving capability. The chip can work normally when the power supply voltage VCC is between 1.65V and 5.5V V. And 74LVC1G00 has a variety of small package shapes, It can be widely used in high-end precision instruments, miniaturized low-power handheld devices, artificial intelligence and other fields.

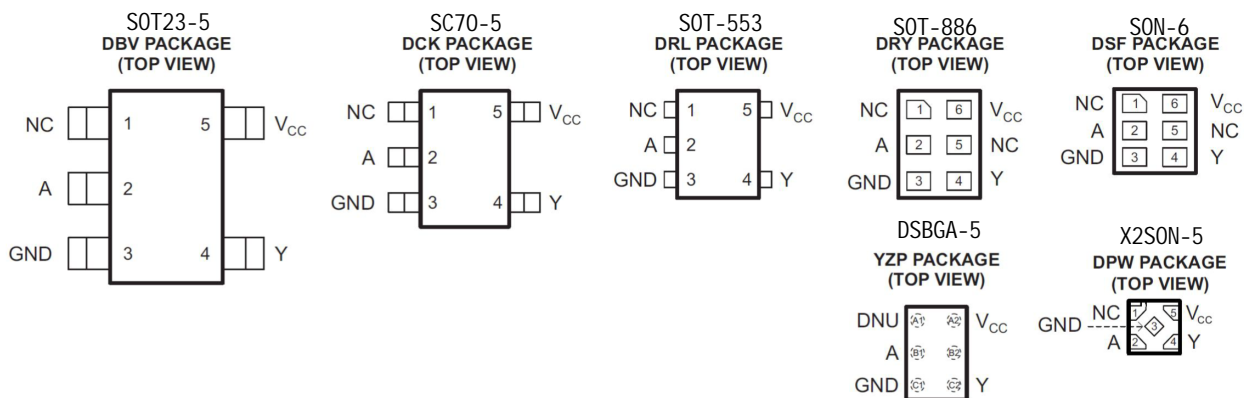
■ Product features

- Low input current: 0.1uA typical
- Low static power consumption: 0.1uA typical
- High output drive: VCC=4.5V, more than 32MA
- Wide working voltage range: 1.65V to 5.5V
- Package form: DBV/DCK/DRL/YZP/ DRY/DSF/ DPW

■ product usage

- Portable audio interface
- digital television
- Wireless headphones, smart watches, etc.
- Blu-ray player and home theater
- Solid state drive
- Smart wearable devices

■ Package form and pin function definition



Name	Pin				Description
	DBV/ DCK/ DRL	DRY/DSF	YZP	DPW	
NC	1	1,5	A1, B2	1	Empty foot
A	2	2	B1	2	Input
GND	3	3	C1	3	Power supply ground
Y	4	4	C2	4	Output
VCC	5	6	A2	5	Power supply positive

Note: NC null pin, no connecting wire inside.

■ Limit parameter

parameter	symbol	limit value	unit
operating voltage	V _{CC}	6.5	V
input	V _{IN}	-0.5~6.5	V
Output voltage (1)	V _{OUT}	-0.5~6.5	V
Single pin output current	I _{OUT}	25	mA
Or V _{CC} current.	I _{CC}	50	mA
Storage temperature	T _S	-65-150	°C
Pin welding temperature	T _W	260, 10s	°C

Note: 1. In the power-off state of V_{CC}=0V, the limit voltage that the output can bear,

2. Limit parameter refers to the limit value that can't be exceeded under any conditions. If it exceeds this limit value, it may cause physical damage such as product deterioration; At the same time, the chip can't work normally when it is close to the limit parameters.

■ Principle logic diagram



■ truth table

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

■ working conditions

project	symbol	test condition	minimum value	typical value	maximum	unit
operating voltage	V _C	-	1.65	-	5.5	V
Input high level voltage	V _{HI}	V _C = 1.65V~1.95V	0.65* V _C	-	-	V
		V _C = 2.3V~2.7V	1.7V	-	-	
		V _C = 3V~5.5V	0.7* V _C	-	-	
Input high level voltage	V _{HI}	V _C = 1.65V~1.95V	-	-	0.35* V _C	V
		V _C = 2.3V~2.7V	-	-	0.7	
		V _C = 3V~5.5V	-	-	0.3* V _C	
input voltage	V _I	-	0	-	5.5	V
Output voltage	V _O	-	0	-	V _C	V
High level output current	I _{OH}	V _C = 1.65V	-	-	-4	mA
		V _C = 2.3V	-	-	-8	
		V _C = 3V	-	-	-16	
		V _C = 4.5V	-	-	-32	
Low level output current	I _{OL}	V _C = 1.65V	-	-	4	mA
		V _C = 2.3V	-	-	8	
		V _C = 3V	-	-	16	
		V _C = 4.5V	-	-	32	

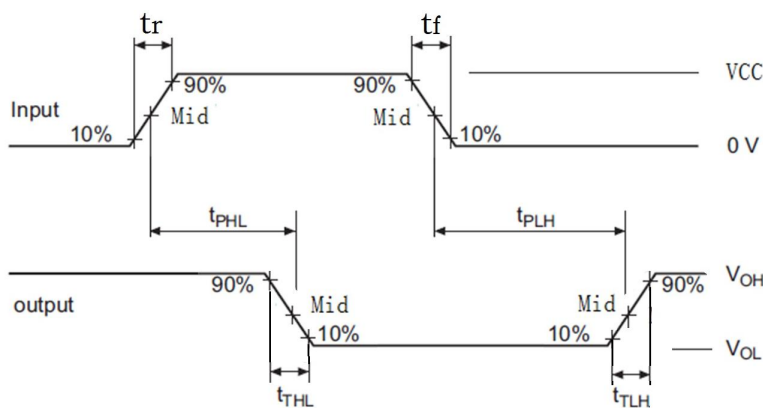
Electrical characteristics

Electrical characteristics of DC: $T_a=25^{\circ}\text{C}$

project	symbol	test condition	V	typical value	maximum	unit	
High level load voltage	V_{OH}	$I_{OH} = -100\mu\text{A}$	1.65V~5.5V	1.64	-	V	
		$I_{OH} = -4\text{ mA}$	1.65V	1.47	-		
		$I_{OH} = -8\text{ mA}$	2.3V	2.15	-		
		$I_{OH} = -16\text{ mA}$	3V	2.73	-		
		$I_{OH} = -32\text{ mA}$	4.5V	4.0	-		
Low level load voltage	V_{OL}	$I_{OH} = 100\mu\text{A}$	1.65V~5.5V	0.01	-	V	
		$I_{OH} = 4\text{ mA}$	1.65V	0.11	-		
		$I_{OH} = 8\text{ mA}$	2.3V	0.11	-		
		$I_{OH} = 16\text{ mA}$	3V	0.2	-		
		$I_{OH} = 32\text{ mA}$	4.5V	0.35	-		
incoming current	I_I	A	$V_I = 5.5\text{V}$ 或 GND	0~5.5V	0.01	± 5	uA
		B			0.01	± 5	
Turn-off current	I_{OFF}	V_I	$V_I = 5.5\text{V}$	0	0.01	± 10	uA
		V_O	$V_O = 5.5\text{V}$	0	0.01	± 10	
operational current	I_{CC}	$V_I = 5.5\text{V}, I_O = 0$	1.65V~5.5V		0.01	10	uA
		$V_I = \text{GND}, I_O = 0$			0.01	10	
Working current variation value	ΔI_{CC}	A= $V_{CC} - 0.6\text{V}$ B= V_{CC} 或 GND	3V~5.5V		25	-	uA
		B= $V_{CC} - 0.6\text{V}$ A= V_{CC} 或 GND			25	-	

Ac electrical characteristics: $T_a=25^{\circ}\text{C}$ V(298)=5.0V, $t_r = \leq 20\text{ns}$. See test method.

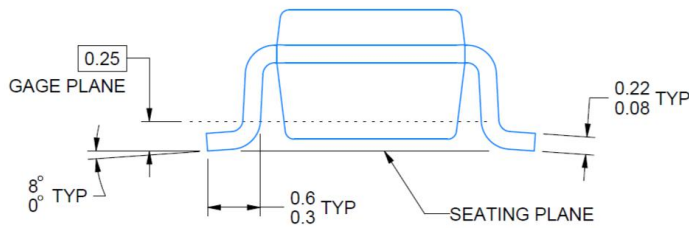
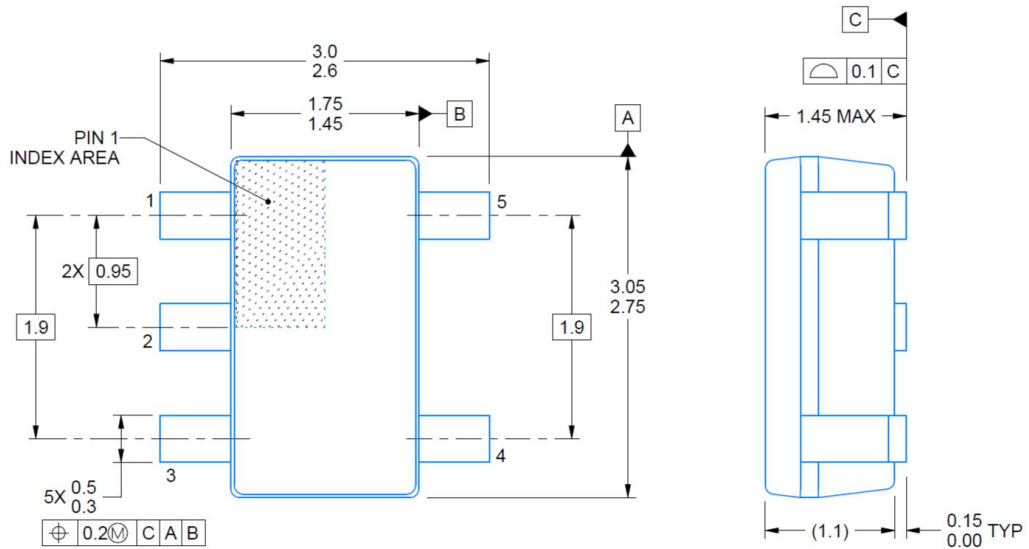
project	symbol	test condition	minimum value	typical value	maximum	unit
Maximum transmission delay time a, B to Y		C = 15pF	-	10	-	ns
		C = 15pF	-	10	-	ns



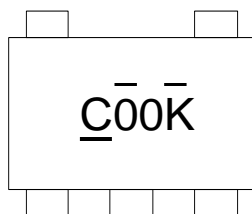
- Note: 1. CL capacitor is external chip capacitor (0603), which is connected close to the output pin, and the capacitor ground is close to the chip GND;
 2. Input: port input level, $f=500\text{kHz}, D=50\%$; $t_r=t_f \leq 20\text{ns}$;
 3. Output: Y-terminal output test.

■ Encapsulated information

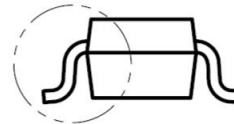
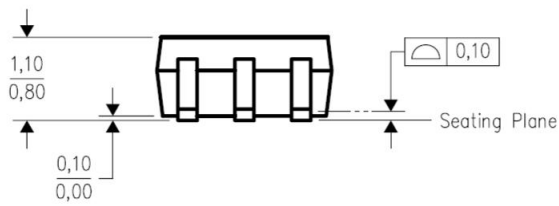
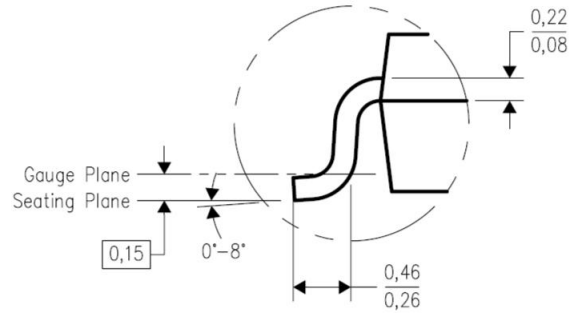
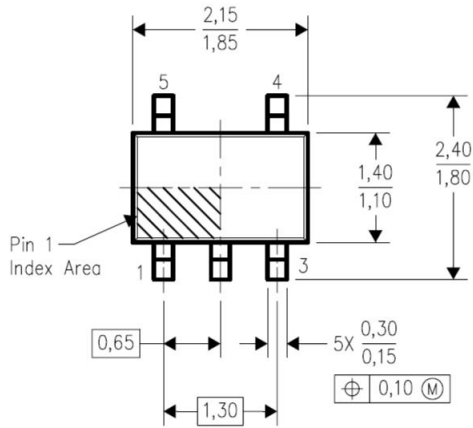
DBV (SOT23-5)



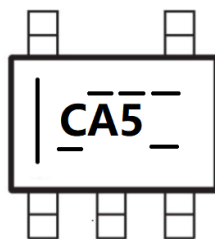
■ Marking



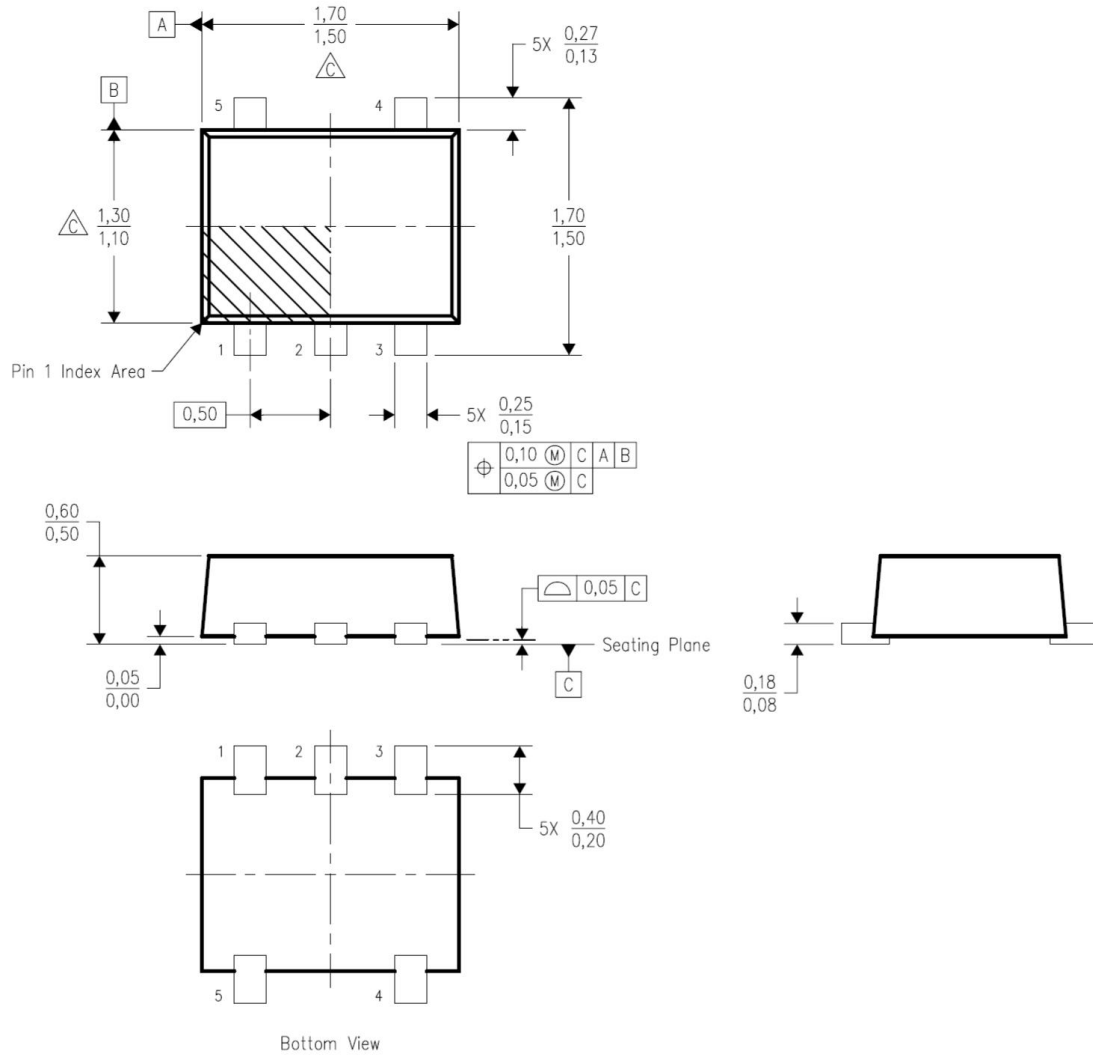
DCK (SC70-5)



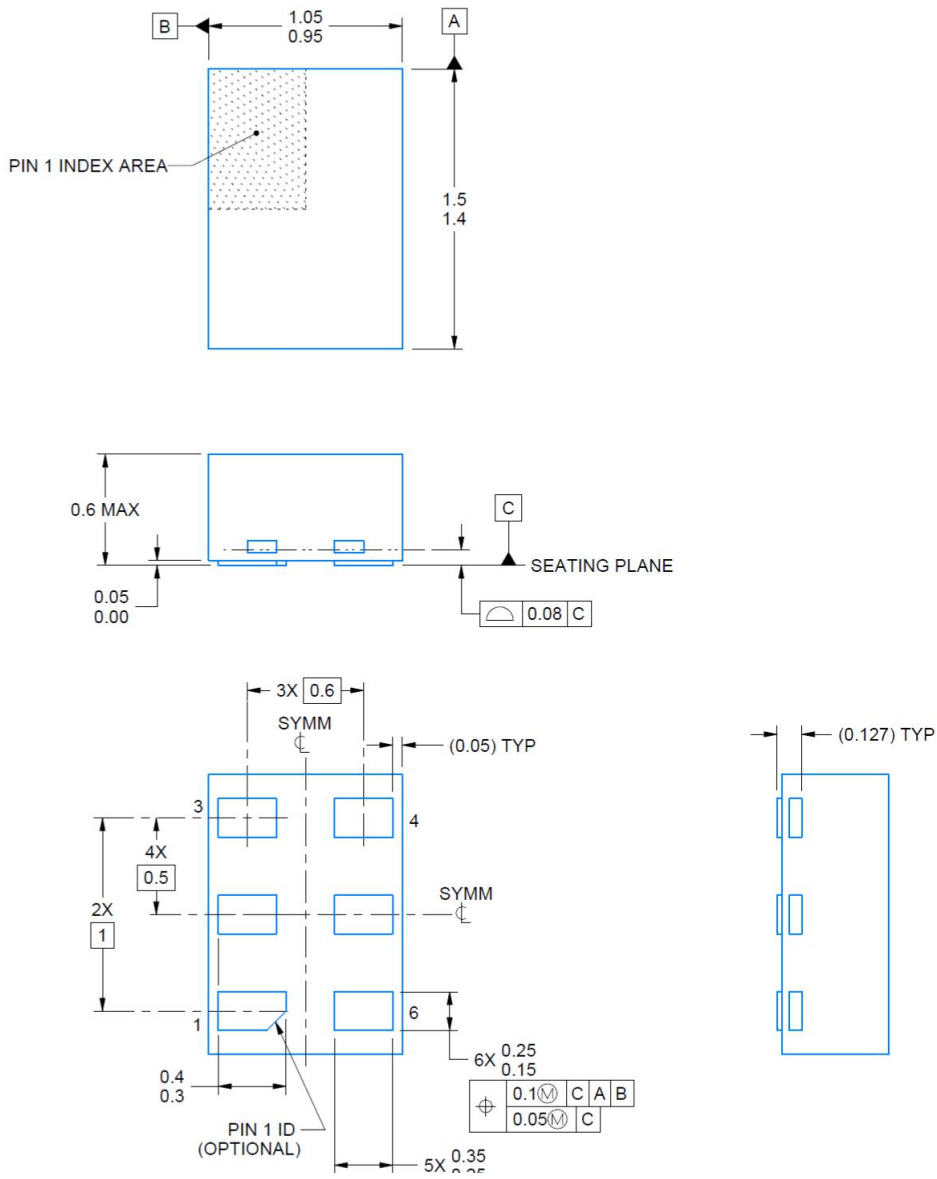
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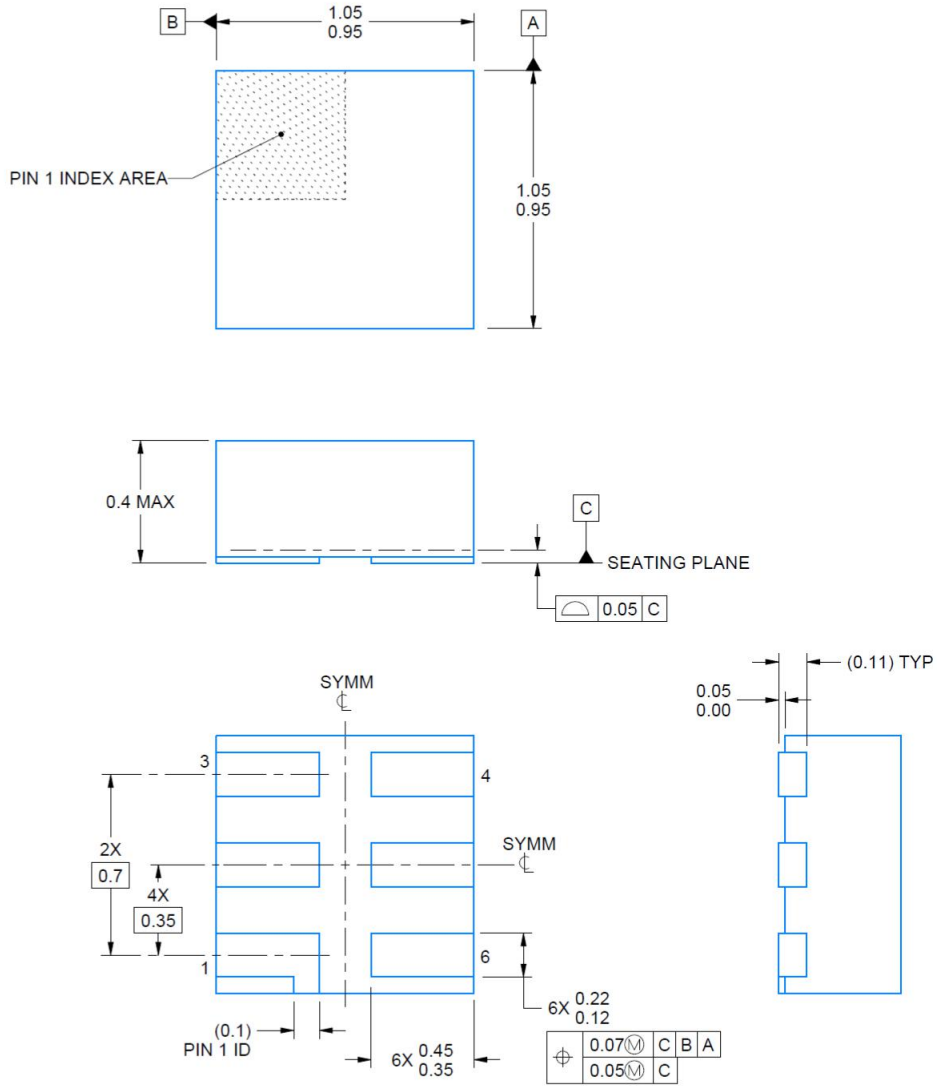
DRL (SOT-553)



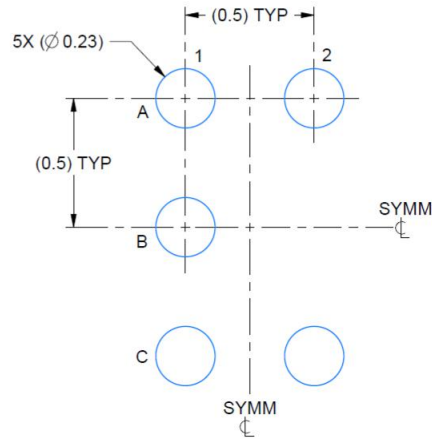
DRY (SOT-886)



DSF (SON-6)



YZP (DSBGA-5)



LAND PATTERN EXAMPLE
SCALE:40X



DPW (X2SON-4)

